



# 60 V NPN MEDIUM POWER TRANSISTOR



CZT651 SOT-223 Plastic Pakage

## **COMPLEMENTRY TYPE – CZT751**

# **Maximum Ratings** @ $T_A = 25^{\circ}C$ unless otherwise specified

PARAMETER	SYMBOL	VALUE	UNIT
Collector-Base Voltage	V <sub>cbo</sub>	80	V
Collector-Emitter Voltage	V <sub>CEO</sub>	60	V
Emitter-Base Voltage	V <sub>EBO</sub>	5	V
Continuous Collector Current	I <sub>c</sub>	3	А
Peak Pulse Current	I <sub>CM</sub>	6	А

#### **Thermal Characteristics**

PARAMETER	SYMBOL	VALUE	UNIT
Power Dissipation at T <sub>A</sub> =25°C	P <sub>D</sub>	2	W
Operating and Storage Temperature Range	Τ <sub>J</sub> , Τ <sub>stg</sub>	-55 to 150	°C





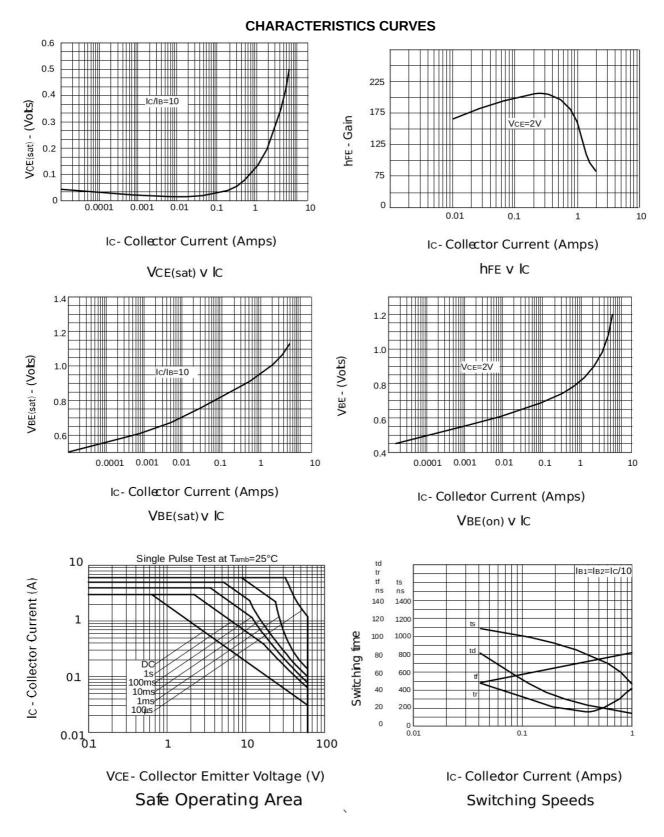
PARAMETER	SYMBOL	TEST CONDITION	MIN	TYP	MAX	UNIT
Collector-Base Breakdown Voltage	V <sub>(BR)CBO</sub>	Ι <sub>c</sub> = 100μΑ	80			V
Collector-Emitter Breakdown Voltage *	$V_{(BR)CEO}$	I <sub>c</sub> = 10mA	60			V
Emitter-Base Breakdown Voltage	V <sub>(BR)EBO</sub>	Ι <sub>Ε</sub> = 100μΑ	5			V
Collector Cut-off Current	۱ <sub>сво</sub>	V <sub>CB</sub> = 60V			0.1	μA
		$V_{CB} = 60V, T_{amb} = 100^{\circ}C$			10	μA
Emitter Cut-off Current	ا <sub>EBO</sub>	V <sub>EB</sub> = 4V			0.1	μA
Collector-Emitter Saturation Voltage *	V <sub>CE(SAT)</sub>	I <sub>c</sub> = 1A, I <sub>B</sub> = 100mA		0.12	0.3	V
		I <sub>c</sub> = 3A, I <sub>B</sub> = 300mA		0.43	0.6	V
Base-Emitter Saturation Voltage *	V <sub>CE(SAT)</sub>	I <sub>c</sub> = 1A, I <sub>B</sub> = 100mA		0.9	1.25	V
Base-Emitter Turn-On Voltage *	V <sub>BE(ON)</sub>	I <sub>c</sub> = 1A, V <sub>ce</sub> = 2V		0.8	1.0	V
DC Current Gain *		I <sub>c</sub> = 50mA, V <sub>ce</sub> = 2V	70	200		
	h <sub>FE</sub>	I <sub>c</sub> = 500mA, V <sub>ce</sub> = 2V	100	200	300	
		$I_{c} = 1A, V_{ce} = 2V$	80	170		
		I <sub>c</sub> = 2A, V <sub>ce</sub> = 2V	40	80		
Current Gain-Bandwidth Product *	f <sub>T</sub>	$V_{ce} = 5V, I_{c} = 100mA,$ f=100MHz	140	175		MHz
Turn-On Time	t <sub>on</sub>	V <sub>cc</sub> = 10V, I <sub>c</sub> = 500mA		45		ns
Turn-Off Time	t <sub>off</sub>	I <sub>B1</sub> = I <sub>B2</sub> = 50mA		800		ns
Output Capacitance *	C <sub>obo</sub>	V <sub>CB</sub> = 10V. f = 1MHz			30	pF

## **Electrical Characteristics** @ $T_A$ = 25°C unless otherwise specified

\* Measured under pulsed conditions. Pulse width =  $300\mu$ s. Duty cycle  $\leq 2\%$ 





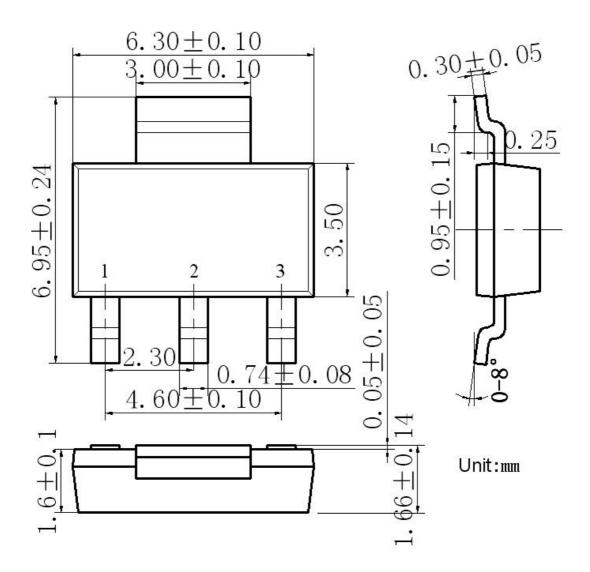


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## PACKAGE OUTLINE AND DIMENSION millimeters(mm)



1. BASE

2. COLLECTOR

3. EMITTER

Data Sheet





**Customer Notes:** 

#### **Component Disposal Instructions**

1. CDIL Semiconductor Devices are RoHS compliant, customers are requested to please dispose as per prevailing Environmental Legislation of their Country.

2. In Europe, please dispose as per EU Directive 2002/96/EC on Waste Electrical and Electronic Equipment (WEEE).

#### DISCLAIMER

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